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400.Garden.City.Plaza Garden.City.New.York 5/1/15 (516) 742-4343 - Telephone (516) 742-4366 - Facsimile e:mail: intrprop@ssmp.com

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То:		miner C.Q. Nguyen up Art Unit: 2811		From:	Leslie S. Szivos, P	Ph.D.
Fax:	703-	872-9306		Pages:	7 including cover	
Phone				Date:	8/31/2004	
Re:	Tze-chiang Chen, et al. U.S. Patent Appln. No. 10/700,085 Our Docket: YOR920030586US1 (17201		CC:			
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The following is attached hereto:

- 1. Amendment Transmittal in duplicate
- 2. Response under 37 CFR 1.111 and 1.143
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and the same of th	ANSMISSION BY FAC	SIMILE (37 CFR 1.8)	Docket No.
Applicant(s): Tze-chiang(G	ien, et al.		YOR920030586US1 (17201)
Application No. Filing Date		Examiner	Group Art Unit
10/700,085 11/3/2003		C.Q. Nguyen	2811
Invention: METHOD FOR SUBSTRATES	FABRICATING SIGe-ON-II	NSULATOR (SGOI) AND Ge-ON	V-INSULATOR (GOI)
I hereby certify that this _		NSE UNDER 37 CFR 1.111 AND (Identify type of correspondence) nt and Trademark Office (Fax. N	_
		It and Trademark Office (Fax. 14	0. 703-872-9300
on August 31, 200	04		
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CERTIFICATE OF Applicant(s) **-Fze-chian	TRANSMISSION BY FAC	SIMILE (37 CFR 1.8)	Docket No. YORO20030586US1 (17201)
Application No. 10/700,085	Filing Date 11/3/2003	Examiner C.Q. Nguyen	Group Art Unit 2811
Invention: METHOD F SUBSTRATI	I OR FABRICATING SIGE-ON-IT ES	NSULATOR (SGOI) AND Ge-C	ON-INSULATOR (GOI)
I hereby certify that this		NSE UNDER 37 CFR 1.111 ANI (Identify type of correspondence)	
	nitted to the United States Pater	it and Trademark Office (Fax.	No. <u>703-872-9306</u> )
On August 31 (Date)			
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	<u></u>	Leslie S. Szivo	-,-,-,-
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		(Signature)	
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AMENDMENT TRANSMITTAL LETTER (Large Entity)								
Applicant(s): Tze-chiang(chen, et al.						Docket.No. YOR920030586US1-(17201)		
					$\exists$	2.1		
Application No. 10/700,085	Filing Date 11/3/2003	Examiner CO Navyan		Customer 1 23389	<b>10.</b>	Group Art Unit 2811		
		C.Q. Nguyen					2805	
	Invention: METHOD FOR FABRICATING SIGE-ON-INSULATOR (SGOI) AND GE-ON-INSULATOR (GOI) SUBSTRATES							
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1		in the above-identified a smitted as shown below	• •	ion.				
		CLAIMS AS AM	ENDE	)				
	CLAIMS REMAINING	HIGHEST#	NUMBI	ER EXTRA		RATE	ADDITIONAL	
	AFTER AMENDMENT	PREV. PAID FOR	CLAIMS	PRESENT			FEE	
TOTAL CLAIMS	68 -	68 =		0	x	\$18.00	\$0.00	
INDEP. CLAIMS	6 -	6 =		0	x	\$86.00	\$0.00	
Multiple Dependen	Multiple Dependent Claims (check if applicable) \$0.0						\$0.00	
		TOTAL ADDITIONAL	FEE FC	R THIS AM	EN	DMENT	\$0.00	
☐ Please cha☐ A check in ☑ The Direct communic ☑ Any a	ation or credit any ove dditional filing fees re		tee is of the following the fo	lowing fees 50-0510	)/ <b>118</b>	<b>M</b>	S	
Leslie S. Szivos, P Registration No. 3			class in	ify that this mall under 37 C. ents, R.O. Box 1	doc F.R. 450,	ument and fee is with the U.S.		
cc:				Typed or Printed	Nan	se of Person Mailing	Correspondence	

AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Tize-chiang(Chen, et al.					Docket No. YOR920030586US17(17201)		
Application No.	Filing Date		To		1		
Application No. 10/700,085	Filing Date 11/3/2003	Examiner C.Q. Nguyen	23389	No. Group Art Uni 2811	t Confirmation No. 2805		
Invention: METHOD FOR FABRICATING SIGE-ON-INSULATOR (SGOI) AND GE-ON-INSULATOR (GOI) SUBSTRATES							
		COMMISSIONER FO	R PATENTS:				
Transmitted herew	ith is an amendment	in the above-identified a	application.				
The fee has been	calculated and is trans	smitted as shown below	<b>.</b>				
		CLAIMS AS AM	ENDED		· · · · · · · · · · · · · · · · · · ·		
	CLAIMS REMAINING	HIGHEST#	NUMBER EXTRA		ADDITIONAL		
	AFTER AMENDMENT	PREV. PAID FOR	CLAIMS PRESENT	RATE	FEE		
TOTAL CLAIMS	68 -	68 =	0	x \$18.00	\$0.00		
INDEP. CLAIMS	6 -	6 =	0	x \$86.00	\$0.00		
Multiple Dependent Claims (check if applicable)							
		TOTAL ADDITIONAL I	FEE FOR THIS AN	IENDMENT	\$0.00		
<ul> <li>No additional fee is required for amendment.</li> <li>□ Please charge Deposit Account No. in the amount of</li> <li>□ A check in the amount of to cover the filing fee is enclosed.</li> <li>☑ The Director Is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account 50-0510/IBM</li> <li>☑ Any additional filing fees required under 37 C.F.R. 1.16.</li> <li>☑ Any patent application processing fees under 37 CFR 1.17.</li> </ul>							
Leslie S. Szivos, P. Registration No. 3			class mail-under 37 C. for Patents, P.Q. Box 1	document and fee i			
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